

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
SA40-19EWA	High Efficiency Red (GaAsP/GaP)	WHITE DIFFUSED	12000	44000	Common Anode, Rt. Hand Decimal.

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red	627		nm	I _F =20mA
λ_D [1]	Dominant Wavelength	High Efficiency Red	625		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	High Efficiency Red	45		nm	I _F =20mA
C	Capacitance	High Efficiency Red	15		pF	V _F =0V;f=1MHz
V _F [2]	Forward Voltage Per Segment Or (DP)	High Efficiency Red	8.0 (4.0)	10.0 (5.0)	V	I _F =20mA
I _R	Reverse Current Per Segment Or (DP)	High Efficiency Red		20 (10)	uA	V _R =20V (V _R =10V)

Notes:

1.Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

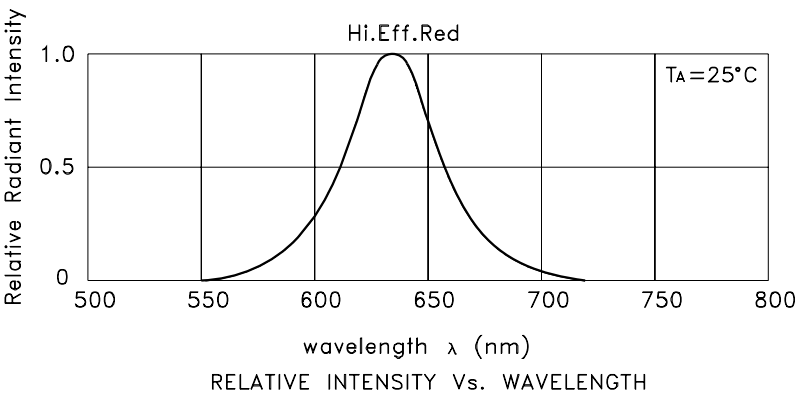
Absolute Maximum Ratings at TA=25°C

Parameter	High Efficiency Red	Units
Power dissipation Per Segment Or (DP)	600 (150)	mW
DC Forward Current Per Segment Or (DP)	60 (30)	mA
Peak Forward Current [1] Per Segment Or (DP)	320 (160)	mA
Reverse Voltage Per Segment Or (DP)	20 (10)	V
Operating / Storage Temperature	-40°C To +85°C	
Lead Solder Temperature[2]	260°C For 3-5 Seconds	

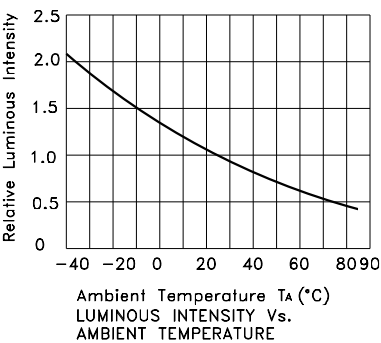
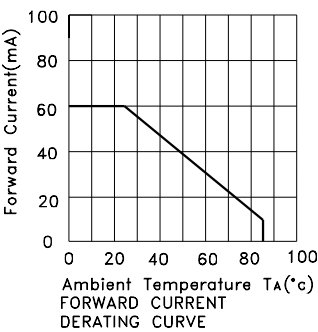
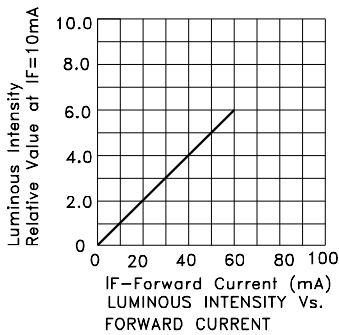
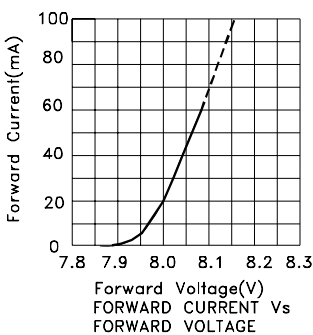
Notes:

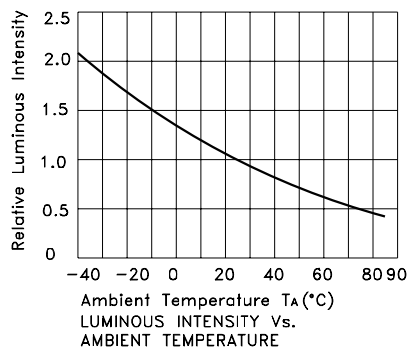
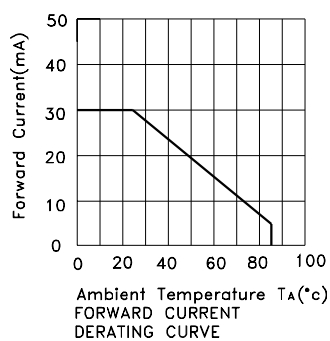
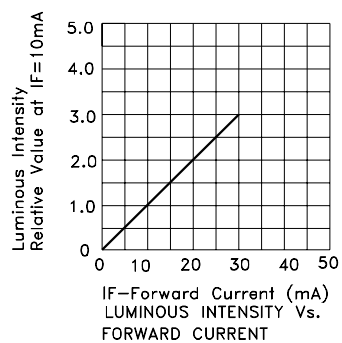
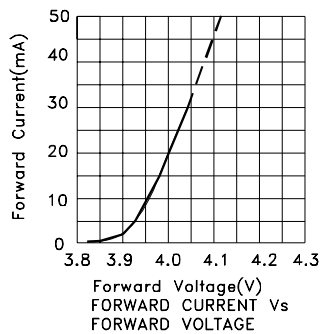
1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.



High Efficiency Red SA40-19EWA





PACKING & LABEL SPECIFICATIONS

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